

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application:

LISTING OF CLAIMS:

1. (currently amended): A compound semiconductor light-emitting device comprising a substrate having a major surface and a side surface and having a light-emitting layer provided on the major surface of said substrate, wherein at least a part of a substrate portion of the device side surface has recessed portions inwardly extended in a side direction of the device, and wherein the recessed portions have a circular shape in cross section.

2. (original): A light-emitting device according to claim 1, wherein at least a part of a compound semiconductor portion of the device side surface has recessed portions in a side direction of the device.

3. (previously presented): A light-emitting device according to claim 1, wherein the light-emitting layer comprises an n-type or p-type compound semiconductor and is of the pn junction type.

4. (previously presented): A light-emitting device according to claim 1, wherein the substrate is selected from the group consisting of a sapphire, a SiC and a III-V Group compound semiconductor single crystal.

5. (currently amended): A light-emitting device according to ~~[[4]]~~claim 1, wherein ~~recessed portions are existing maintaining~~ a distance of 4 to 40 μm is maintained between the adjacent recessed portions.

6. (currently amended): A light-emitting device according to claim 1, wherein individual ones of the recessed portions have a depth of 0.5 to 10 μm and a width of 1 to 20 μm .

7. (previously presented): A light-emitting device according to claim 1, wherein the compound semiconductor light-emitting device is of the flip-chip type.

Claims 8-17. (canceled).

18. (previously presented): A lamp comprising a compound semiconductor light-emitting device of claim 1.

19. (original): A source of light comprising a lamp of claim 18.